Diode Semiconductor Device - Page 1 of 1



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Inclosure Material
Inclosure Material:
Glass and metal
Overall Length:
Between 0.230 inches and 0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.108 inches and 0.140 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-14
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
0.10 microamperes forward current, average peak
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Νο
Fiig:
A110a0